NSN 5961-01-215-1556

Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-215-1556

Inclosure Material:
Metal
Overall Length:
0.300 inches
Terminal Length:
1.300 inches
Overall Diameter:
0.140 inches
Mounting Method:
Terminal
Features Provided:
Hermetically sealed case and quality assurance level tx
Semiconductor Material:
Silicon
Voltage Rating In Volts Per Characteristic:
43.7 reverse voltage, peak
Voltage Tolerance In Percent:
-5.0/+5.0
Current Rating Per Characteristic:
1.00 milliamperes source cutoff current horsepower metric
Power Rating Per Characteristic:
2.5 watts small-signal input power, common-collector major
Maximum Operating Tempurature Per Measurement Point:
175.0 degrees celsius ambient air
Test Data Document:
81349-mil-s-19500 specification (includes engineering type bulletins, brochures, etc., that reflect specification type data in specification
format; excludes commercial catalogs, industry directories, and similar trade publications, reflecting general type data on certain
environmental and performance requirements and test conditions that are shown as "typical", "average", "", etc.).
Terminal Type And Quantity:
2 uninsulated wire lead
Specification Data:
81349-mil-s-19500/551 government specification
Shelf Life:
N/a
Unit Of Measure:

Demilitarization:
No
Fiig:
A110a0